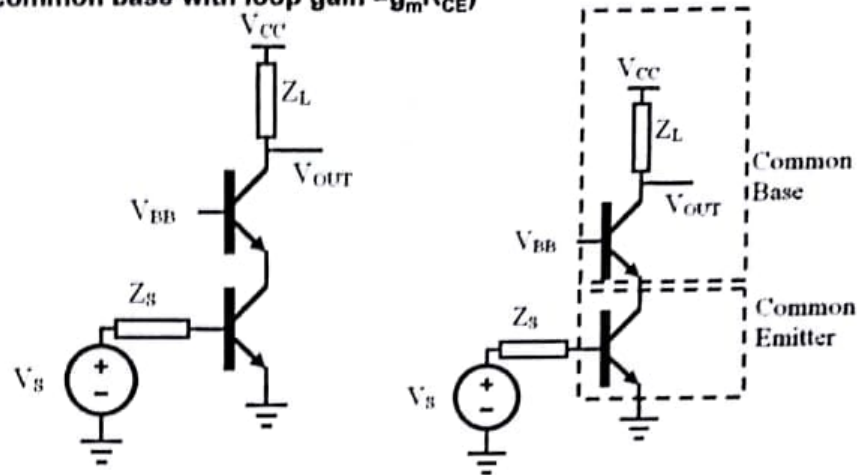


## Cascode amplifier

- Wideband voltage amplifier
- CE stage operates at gain  $\approx -1$ , minimising miller loading of input.
- CB gives all the voltage gain, acting as transimpedance of value  $Z_L$
- The cascode has a much higher output impedance (other than  $Z_L$ ) than the CE amplifier (the common emitter Early resistance acts as series-series feedback to the common base with loop gain  $\approx g_m R_{CE}$ )



Points to be noted:

① The cascode is a two stage amp. Composed of Transconductance (CE) amp. followed by a Current buffer (CB)

② Characteristics of Cascode amp: (Advantages)

① Higher o/p - o/p isolation

② ~~Higher~~ <sup>Modest</sup> o/p impedance

③ Higher o/p impedance

④ Higher gain

⑤ Higher Bandwidth

⑥ Reduced Miller's Capacitive effect

⑦ Cascode Configuration is Very stable (i.e. no self oscillations occur)

⑧ High slew Rate

③ Disadvantages: Needs 2 transistors and require high supply voltages.

④ Application area: ① Very useful in multiplying mixed circuit in Superhetrodyne receivers. [RF is given base of CE and Local oscillator signal is given at base of CB stages.]  
② As a Current Mirror etc.

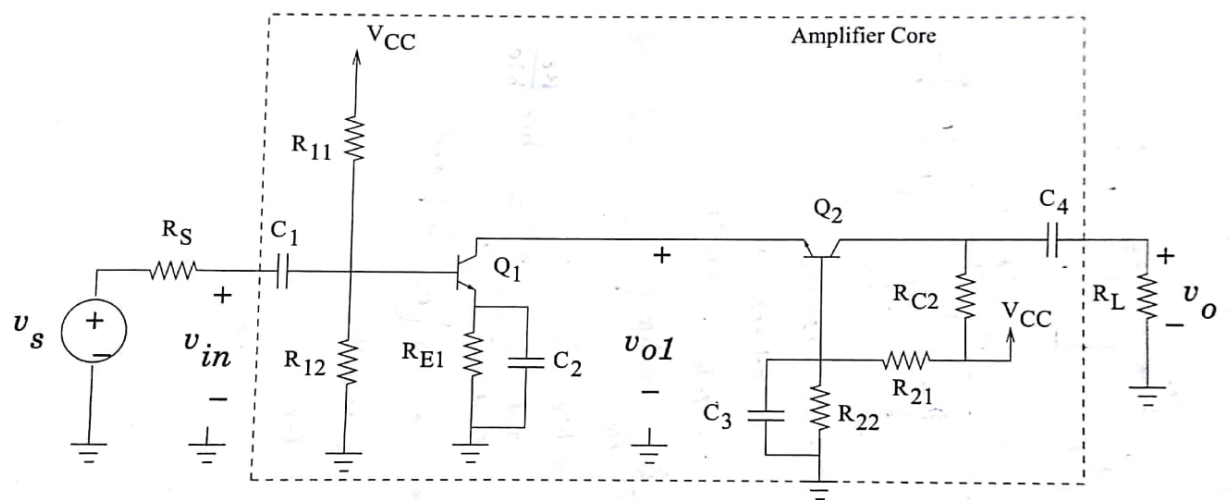
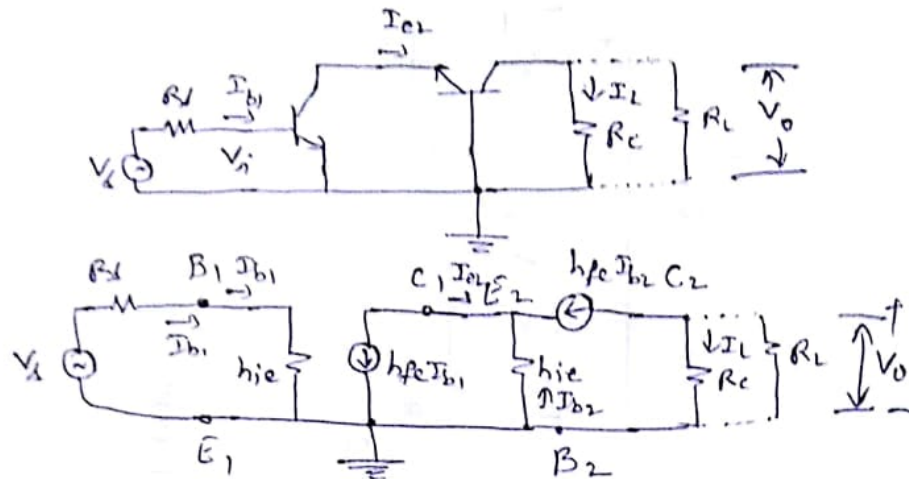


Figure 1. Simple BJT cascode amplifier core.

### Analysis:

Ac equivalent ckt can be obtained as below



$$\begin{aligned} \textcircled{1} \quad A_I &= \frac{I_L}{I_{b1}} ; I_L = -h_{fe} I_{b2} \\ I_{c2} &= -(1+h_{fe}) I_{b2} \\ &= -h_{fe} I_{b1} = -(1+h_{fe}) I_{b2} \end{aligned}$$

$$\therefore A_I = \frac{-h_{fe}}{1+h_{fe}} \approx -h_{fe}$$

$$\textcircled{2} \quad R_i = \frac{V_i}{I_{b1}} \approx h_{ie}$$

$$\textcircled{3} \quad A_V = \frac{V_o}{V_i} = \frac{I_L R_c}{I_{b1} R_i} = A_I \frac{R_c}{R_i} = -h_{fe} \frac{R_c}{h_{ie}}$$

$$\textcircled{4} \quad Y_o = \frac{I_o}{V_o} = 0 \Rightarrow R_o = \infty \text{ and}$$

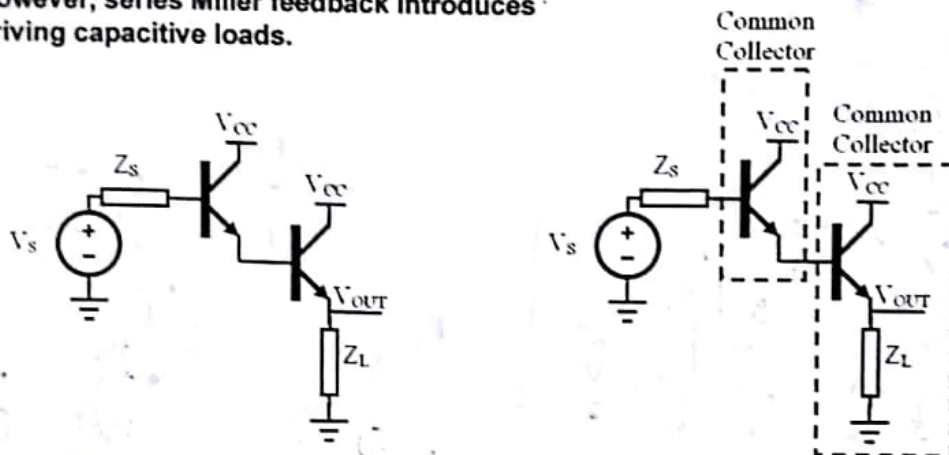
$$R_o' = R_o \parallel R_c$$

$$R_o' \approx R_c$$

-END-

## Darlington pair (SUPER-ALFA PAIR)

- The darlington pair is a high gain power amplifier it has:
  - Unity voltage gain
  - High current gain equal to the product of the two transistor current gains
- Often used as a single transistor for higher beta. But :
- has high input DC voltage drop
- Good frequency response due to the absence of shunt Miller feedback.
- However, series Miller feedback introduces driving capacitive loads.



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Points to be noted:

- ① It consists of 2 CC stages cascaded.
- ② characteristics: (Adv.)
  - Ⓐ V. High current gain
  - Ⓑ V. High input impedance
  - Ⓒ Easy to ~~obtain~~ made from 2 transistors.
  - Ⓓ Available as a single module with 3 terminals.
  - Ⓔ unity voltage gain
  - Ⓕ Good frequency response
  - Ⓖ Less effect of Miller's feedback capacitance.
  - Ⓗ V. High power gain.
- ③ Disadvantages:
  - Ⓐ slow Switching speeds
  - Ⓑ Limited Bandwidth (compare to cascade)
  - Ⓒ introduces phase shift. may lead to instability
  - Ⓓ High DC drop i.e. higher overall  $V_{BE}$   
( $= V_{BE1} + V_{BE2}$ )
  - Ⓔ Higher saturation voltage (0.7V) which leads to higher power dissipation.

(P.T.O.)

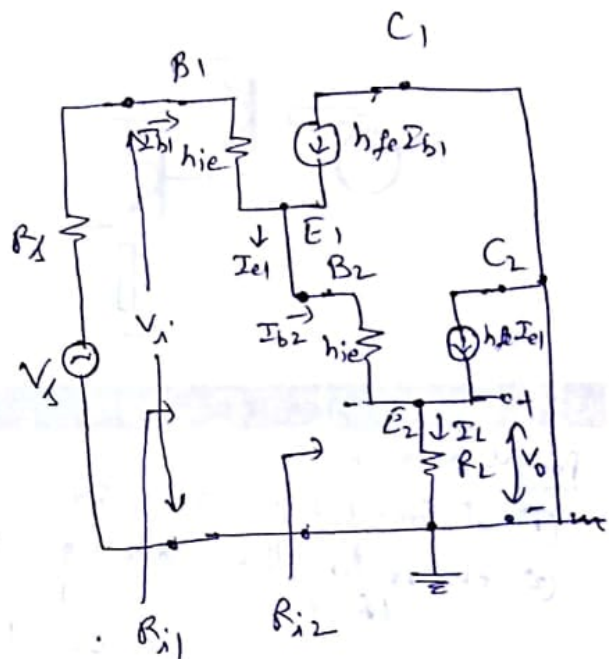
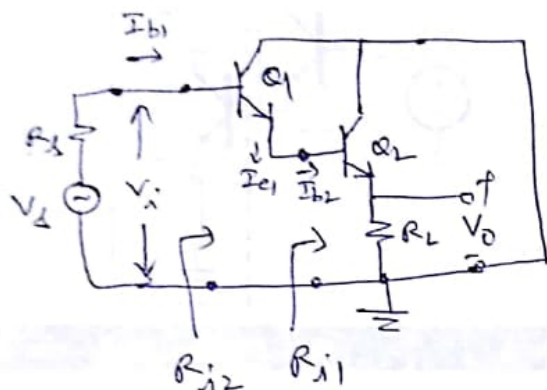


## ④ Application Areas:

- ① where high current gain is needed at low frequencies
- ② Power Regulators
- ③ Audio amplifier o/p stages
- ④ Display drivers
- ⑤ Motor Controllers
- ⑥ Touch and light sensors

## Analysis:

### Ac equivalent



$$① A_I = \frac{I_L}{I_i}$$

$$I_L = I_{b2} + h_{fe} I_{b2} = (1 + h_{fe}) I_{e1}$$

$$= (1 + h_{fe}) (1 + h_{fe}) I_{b1}$$

$$\therefore A_I = (1 + h_{fe})^2$$

$$② R_{i2} = h_{ie} + (1 + h_{fe}) R_L$$

$$\text{or } R_{i1} = \frac{V_i}{I_{b1}} = h_{ie} + (1 + h_{fe}) R_{i2}$$

$$R_{i1} = h_{ie} + h_{ie} (1 + h_{fe}) + (1 + h_{fe})^2 R_L$$

$$R_{i1} \approx (1 + h_{fe})^2 R_L \quad (\because h_{ie} \ll (1 + h_{fe}) R_L) \quad (P.T.O.)$$

$$(3) A_v = \frac{V_o}{V_i} = \frac{I_L R_L}{I_{i1} R_{i1}} = A_I \frac{R_L}{R_{i1}}$$

$$\therefore A_v = (1+h_{fe})^2 \times \frac{R_L}{(1+h_{fe})^2 R_L}$$

$$\boxed{A_v \approx 1}$$

$$(4) \gamma_o = \frac{I_o}{V_o} = \frac{I_L}{V_o} = \frac{I_{e2}}{V_o}$$

$$I_{e2} = (1+h_{fe}) I_{e1}$$

$$I_{e2} = (1+h_{fe})^2 I_{b1}$$

$$\text{but } V_i = R_{i1} I_{b1}$$

$$\therefore I_{b1} = \frac{V_i}{R_{i1}}$$

$$\therefore \gamma_o = \frac{(1+h_{fe})^2 V_i}{R_{i1} V_o}$$

$$\gamma_o = \frac{(1+h_{fe})^2}{R_{i1}}$$

$$\left[ \because \frac{V_o}{V_i} = 1 \right]$$

$$\therefore R_o = \frac{R_{i1}}{(1+h_{fe})^2}$$

$$= \frac{h_{ie} + h_{ie}(1+h_{fe}) + (1+h_{fe})^2 R_L}{(1+h_{fe})^2}$$

$$\boxed{R_o = R_L + \frac{h_{ie}}{(1+h_{fe})} + \frac{h_{ie}}{(1+h_{fe})^2}}$$

$$\boxed{R_o \approx R_L}$$

$$\because h_{fe} \gg 1$$

If  $R_L = \infty$  then

$$R_o = \infty$$

$$\therefore R_o = \infty \text{ \& } R_o' = R_L$$

-END.-